

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7W139F, TC7W139FU**2-TO-4 LINE DECODER**

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The TC7W139 is a high speed C²MOS 2 to 4 LINE DECODER/DEMUTIPLEXER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the C²MOS low power dissipation.

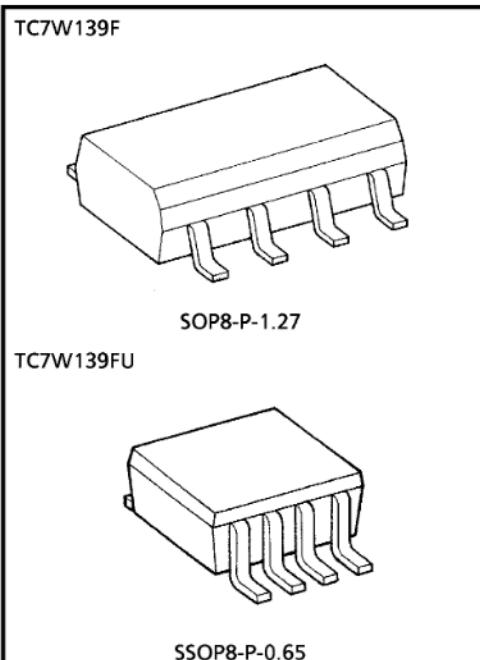
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES

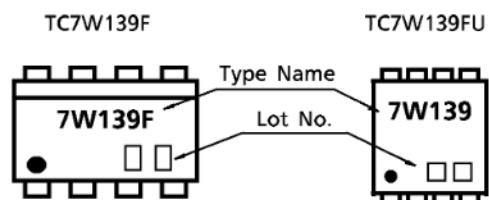
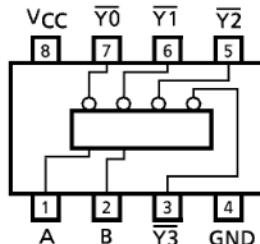
- High Speed $t_{pd} = 6\text{ns}$ (Typ.) at $V_{CC} = 5\text{V}$
- Low Power Dissipation $I_{CC} = 2\mu\text{A}$ (Max.) at $T_a = 25^\circ\text{C}$
- High Noise Immunity $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Output Drive Capability 10 LSTTL Loads
- Symmetrical Output Impedance ... $|I_{OH}| = |I_{OL}| = 4\text{mA}$
- Balanced Propagation Delays $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range ... $V_{CC(\text{opr})} = 2\text{V} \sim 6\text{V}$

TRUTH TABLE

| INPUTS | | OUTPUTS | | | | SELECTED OUTPUT |
|--------|---|-------------|-------------|-------------|-------------|-----------------|
| SELECT | | \bar{Y}_0 | \bar{Y}_1 | \bar{Y}_2 | \bar{Y}_3 | |
| B | A | | | | | |
| L | L | L | H | H | H | \bar{Y}_0 |
| L | H | H | L | H | H | \bar{Y}_1 |
| H | L | H | H | L | H | \bar{Y}_2 |
| H | H | H | H | H | L | \bar{Y}_3 |



Weight SOP8-P-1.27 : 0.05g (Typ.)
 SSOP8-P-0.65 : 0.02g (Typ.)

MARKING**PIN ASSIGNMENT (TOP VIEW)**

MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|-------------------------------------|------------------|-----------------------------|------|
| Supply Voltage Range | V _{CC} | - 0.5~7 | V |
| DC Input Voltage | V _{IN} | - 0.5~V _{CC} + 0.5 | V |
| DC Output Voltage | V _{OUT} | - 0.5~V _{CC} + 0.5 | V |
| Input Diode Current | I _{IK} | ± 20 | mA |
| Output Diode Current | I _{OK} | ± 20 | mA |
| DC Output Current | I _{OUT} | ± 25 | mA |
| DC V _{CC} / Ground Current | I _{CC} | ± 25 | mA |
| Power Dissipation | P _D | 300 | mW |
| Storage Temperature | T _{stg} | - 65~150 | °C |
| Lead Temperature 10s | T _L | 260 | °C |

RECOMMENDED OPERATING CONDITIONS

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|--------------------------|---------------------------------|---|------|
| Supply Voltage | V _{CC} | 2~6 | V |
| Input Voltage | V _{IN} | 0~V _{CC} | V |
| Output Voltage | V _{OUT} | 0~V _{CC} | V |
| Operating Temperature | T _{opr} | - 40~85 | °C |
| Input Rise and Fall Time | t _r , t _f | 0~1000 (V _{CC} = 2.0V) 0~ 500 (V _{CC} = 4.5V) 0~ 400 (V _{CC} = 6.0V) | ns |

DC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITION | V_{CC} | Ta = 25°C | | | Ta = - 40~85°C | | UNIT |
|---------------------------|----------|-------------------------------|---------------------|-----------|------|-----------|----------------|-----------|---------|
| | | | | MIN. | TYP. | MAX. | MIN. | MAX. | |
| High-Level Input Voltage | V_{IH} | — | 2.0 | 1.5 | — | — | 1.5 | — | V |
| | | | 4.5 | 3.15 | — | — | 3.15 | — | |
| | | | 6.0 | 4.2 | — | — | 4.2 | — | |
| Low-Level Input Voltage | V_{IL} | — | 2.0 | — | — | 0.5 | — | 0.5 | V |
| | | | 4.5 | — | — | 1.35 | — | 1.35 | |
| | | | 6.0 | — | — | 1.8 | — | 1.8 | |
| High-Level Output Voltage | V_{OH} | $V_{IN} = V_{IH}$ or V_{IL} | $I_{OH} = -20\mu A$ | 2.0 | 1.9 | 2.0 | — | 1.9 | V |
| | | | $I_{OH} = -4mA$ | 4.5 | 4.4 | 4.5 | — | 4.4 | |
| | | | $I_{OH} = -5.2mA$ | 6.0 | 5.9 | 6.0 | — | 5.9 | |
| Low-Level Output Voltage | V_{OL} | $V_{IN} = V_{IH}$ or V_{IL} | $I_{OL} = 20\mu A$ | 2.0 | — | 0.0 | 0.1 | — | V |
| | | | $I_{OL} = 4mA$ | 4.5 | — | 0.0 | 0.1 | — | |
| | | | $I_{OL} = 5.2mA$ | 6.0 | — | 0.0 | 0.1 | — | |
| Input Leakage Current | I_{IN} | $V_{IN} = V_{CC}$ or GND | 6.0 | — | — | ± 0.1 | — | ± 1.0 | μA |
| Quiescent Supply Current | I_{CC} | $V_{IN} = V_{CC}$ or GND | 6.0 | — | — | 2.0 | — | 20.0 | |

AC ELECTRICAL CHARACTERISTICS ($C_L = 15pF$, $V_{CC} = 5V$, $Ta = 25^\circ C$)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|---|------------------------|----------------|------|------|------|------|
| Output Transition Time | t_{TLH} t_{THL} | — | — | 4 | 8 | ns |
| Propagation Delay Time (A, B- \bar{Y}) | t_{pLH} t_{pHL} | | — | 12 | 22 | |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50\text{pF}$, Input $t_r = t_f = 6\text{ns}$)

| PARAMETER | SYMBOL | TEST CONDITION | V_{CC} | Ta = 25°C | | | Ta = -40~85°C | | UNIT |
|---------------------------------|-----------|----------------|----------|-----------|------|------|---------------|------|------|
| | | | | MIN. | TYP. | MAX. | MIN. | MAX. | |
| Output Transition Time | t_{TLH} | — | 2.0 | — | 30 | 75 | — | 95 | ns |
| | t_{THL} | | 4.5 | — | 8 | 15 | — | 19 | |
| | | | 6.0 | — | 7 | 13 | — | 16 | |
| Propagation Delay Time (A, B-Y) | t_{pLH} | — | 2.0 | — | 45 | 130 | — | 165 | |
| | t_{pHL} | | 4.5 | — | 15 | 26 | — | 33 | |
| | | | 6.0 | — | 13 | 22 | — | 28 | |
| Input Capacitance | C_{IN} | — | | — | 5 | 10 | — | 10 | pF |
| Power Dissipation Capacitance | C_{PD} | (Note 1) | | — | 46 | — | — | — | |

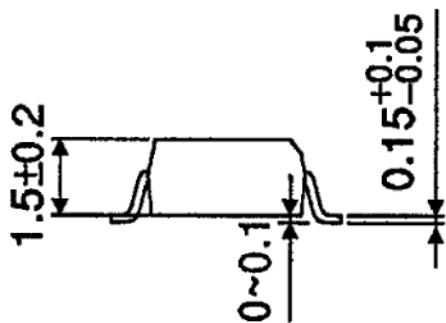
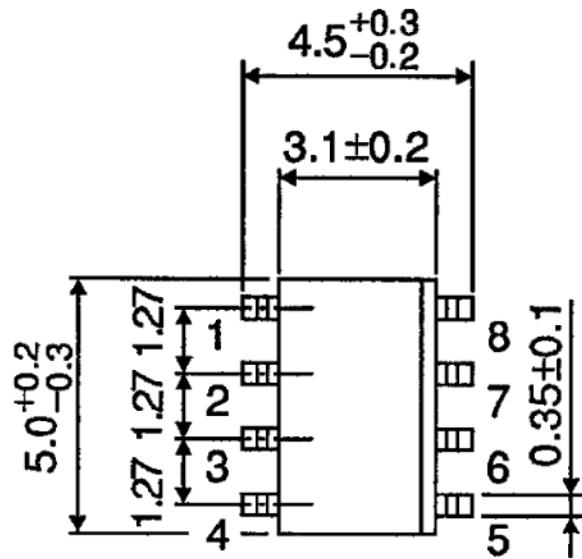
Note 1 : C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

PACKAGE DIMENSIONS
SOP8-P-1.27

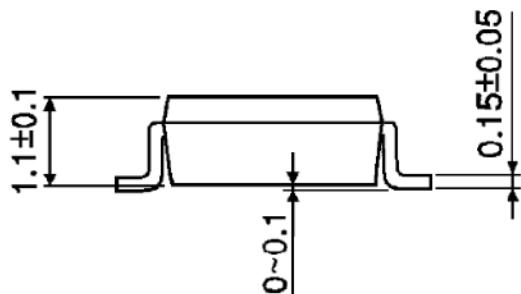
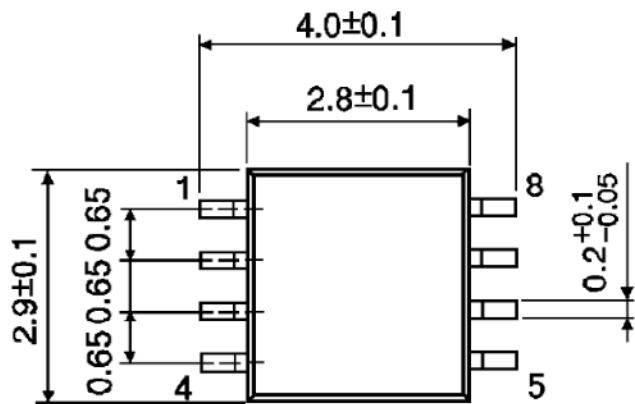
Unit : mm



Weight : 0.05g (Typ.)

PACKAGE DIMENSIONS
SSOP8-P-0.65

Unit : mm



Weight : 0.02g (Typ.)

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